

January 1994

DESCRIPTION

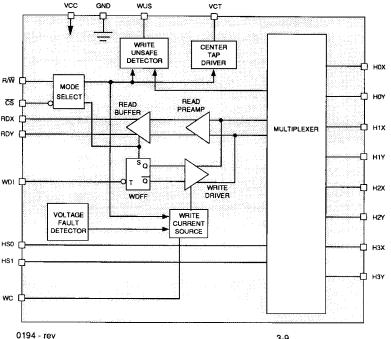
The SSI 32R1203A is a bipolar monolithic integrated circuit designed for use with center-tapped ferrite or MIG recording heads. It provides a low noise read path with a gain of 250 V/V, write current control, and data protection circuitry for as many as 4 channels. Power supply fault protection is provided by disabling the write current generator during power sequencing. A Power Down mode (Idle) is provided to reduce power consumption to less than 10 mW.

The SSI 32R1203A requires only a +5V power supply and is available in a surface mount package.

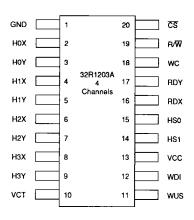
FEATURES

- +5V only power supply
- Low power
 - Pd ≤ 225 mW Read mode
 - Pd ≤ 10 mW Idle mode
- **High Performance**
 - Input noise = 1.2 nV/√Hz max.
 - Input capacitance = 19 pF max.
 - Write current range = 15 50 mA
 - Head voltage swing = 6.0 Vpk
- 250 V/V read gain
- Designed for center-tapped ferrite or MIG heads
- Power supply fault protection
- Includes write unsafe detection
- **Enhanced Write to Read recovery**

BLOCK DIAGRAM WUS



PIN DIAGRAM



20-Lead SOL, SOV

CAUTION: Use handling procedures necessary for a static sensitive component,

FUNCTIONAL DESCRIPTION

WRITE MODE

A source of recording current is provided to the head center tap by an internal voltage reference, VCT. The current is conducted through the head alternately into an HnX terminal or an HnY terminal according to the state of an internal flip-flop. The flip-flop is triggered by the negative transition of the Write Data Input line (WDI). A preceding Read mode selection initializes the write data flip-flop, WDFF, to pass write current through the "X" side of the head. The write current magnitude is determined by the value of an external resistor Rwc connected between WC terminal and GND, and is given by:

Iw = K/Rwc, where K = Write Current Constant

WRITE MODE FAULT DETECT CIRCUIT

Several circuits are dedicated to detecting fault conditions associated with the Write mode. A logical high level will be present at the Write Unsafe (WUS) terminal if any of the following write fault conditions are present:

- Head open
- Head center tap open
- Head shorted
- Head shorted to ground
- No write current
- WDI frequency too low
- Device in Read or Idle mode

The Write Unsafe output is open-collector and is usually terminated by an external resistor connected to VCC. Two negative transitions on WDI, after the fault is corrected, will clear the WUS flag.

A safe condition, WUS low, requires alternating voltage spikes on both HnX and HnY that exceed VCT + 1.5V at a rate equal to or higher than the Minimum Rate of WDI for Safe condition.

In addition, the power supply voltage level is monitored by a circuit that inhibits the write current if VCC is too low to permit valid data recording.

READ MODE

In Read Mode, (R/W high and \overline{CS} low), the circuit functions as a low noise gain selectable differential amplifier. The read amplifier input terminals are determined by the Head Select inputs. The read amplifier outputs (RDX, RDY) are emitter follower sources, providing low impedance outputs. The amplifier polarity is non-inverting between HnX, HnY inputs and RDX, RDY outputs.

IDLE MODE

Taking \overline{CS} high selects the Idle mode which switches the RDX and RDY outputs into a high impedance state and deactivates the device. Power consumption in this mode is held to a minimum.

MODE SELECTION AND INDICATION CIRCUIT

Logical control inputs which select mode and head channel are TTL compatible. Their functions are described in Table 1 and Table 2.

TABLE 1: Head Select Table

| Head Selected | HS1 | HS0 |
|---------------|-----|-----|
| 0 | 0 | 0 |
| 1 | 0 | 1 |
| 2 | 1 | 0 |
| 3 | 1 | 1 |

TABLE 2: Mode Select Table

| Mo Sel | | Selected Mode | Indicating & Fault Outputs |
|---------------|-----|------------------|----------------------------|
| CS | R/W | | wus |
| 1 | х | ldle | high |
| 0 | 1 | Read | high |
| 0 | 0 | Write | active |

PIN DESCRIPTION

| NAME | TYPE | DESCRIPTION |
|--------------------|-----------|--|
| HS0, HS1 | i* | Head Select: Logical combinations select one of four Heads. See Table 1 |
| CS | ı | Chip Select: a low level enables device. Has internal pull-up resistor. |
| R/W | 1* | Read/Write: a high level selects Read mode. Has internal pull-up resistor. |
| WUS | 0* | Write Unsafe: a high level indicates an unsafe writing condition. |
| WDI | l* | Write Data In: negative transition toggles direction of head current. |
| H0X-H3X H0Y-H3Y | 1/0 | X, Y head connections |
| RDX, RDY | O* | X, Y Read Data: differential read signal output. |
| WC | - | Write Current: used to set the magnitude of the write current. |
| VCT | - | Voltage Center Tap: voltage source for head center tap. |
| VCC | - | +5V |
| GND | - | Ground |
| * When more than | one R/W o | device is used, these signals can be wire OR'ed with unselected R/W devices. |

ELECTRICAL SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS

All voltages referenced to GND. Currents into device are positive.

| PARAMETER | | RATING |
|---|------|-------------------------|
| DC Supply Voltage | VCC | -0.3 to +6 VDC |
| Digital Input Voltage Range HS1, HS0, WDI, R/W, CS | | -0.3 to (VCC + 0.3 VDC) |
| Head Port Voltage Range | VH | -0.3 to (VCC + 3.0 VDC) |
| Write Current Pin Voltage | Vwc | -0.3 to (VCC + 0.3 VDC) |
| WUS Pin Voltage Range | Vwus | -0.3 to +6.0 VDC |
| Write Current Zero-Peak | IW | 60 mA |
| RDX, RDY Output Current | lo | -10 mA |
| RDX, RDY Pin Voltage | | VCC + 0.3 VDC |
| VCT Output Current Range | Ivct | -60 mA to +10 mA |
| WUS Output Current Range | Iwus | -0.1 mA to +10 mA |
| Storage Temperature Range | Tstg | -65 to 150°C |
| Package Temperature (20 sec Reflow) | | 215°C |

ELECTRICAL SPECIFICATIONS (continued)

RECOMMENDED OPERATION CONDITIONS

| PARAMETER | CONDITIONS | MIN | NOM | MAX | UNITS |
|----------------------------|------------|------|-----|------|-------|
| DC Supply Voltage VC | | 4.75 | 5.0 | 5.25 | VDC |
| Head Inductance L | h | 1 | | 15 | μН |
| Write Current Range IV | V | 15 | - | 50 | mA |
| Junction Temperature Range | j | +25 | | +135 | °C |

DC CHARACTERISTICS

Unless otherwise specified, recommended operating conditions apply.

POWER SUPPLY

| VCC Supply Current (ICC) | Read Mode | 33 | 44 | mA |
|--------------------------|------------|---------------|-----------------|----|
| | Idle Mode | 1.4 | 2.0 | mA |
| | Write Mode | 31 + lw | 44 + lw | mA |
| Power Dissipation | Read Mode | 165 | 227 | mW |
| | Idle Mode | 7 | 10.5 | mW |
| | Write Mode | 155 + 5 lw | 230 + 5.5 lw | mW |

DIGITAL I/O

| Input Low Voltage CS, R/W WDI, HS0, HS1 | VIL | | | 0.8 | VDC |
|---|-----|--------------|------|---------|-----|
| Input High Voltage CS, R/W WDI, HS0, HS1 | VIH | | 2.0 | | VDC |
| Input Low Current CS, R/W WDI, HS0, HS1 | HL | VIL = 0.4V | -0.4 | | mA |
| Input High Current CS, R/W WDI, HS0, HS1 | IIH | VIH = 2.7V | | 20 | μА |
| WUS Output Low Voltage | VOL | IOL = 4.0 mA | | 0.5 | VDC |
| WUS Output High Current | IOH | VOH = 5.0V | | 100 | μА |

WRITE MODE

| PARAMETER | CONDITIONS | MIN | NOM | MAX | UNITS |
|--|--|---------|-----------|---------|-------|
| Center Tap Voltage VCT | Write Mode/Idle Mode | | Vcc - 0.9 | | VDC |
| Head Current (per side) | Write Mode, Voltage Fault 0 ≤ VCC ≤ 3.9V | -200 | | 200 | μА |
| Write Current Range | 1.0 kΩ ≤ Rwc ≤ 3.3 kΩ | 15 | | 50 | mA |
| Write Current Constant "K" | | 46 | 50 | 54 | mA-kΩ |
| lwc to Head Current Gain | | | 20 | | mA/mA |
| Unselected Head Leakage Current | | | | 85 | μА |
| RDX, RDY Common Mode Output Voltage | | Vcc - 3 | Vcc - 2.4 | Vcc - 2 | VDC |
| WDI Minimum Pulse Width | PWH VIL ≥ 0.2V | | 11 | - | ns |
| See Figure 1 | PWL VIN ≥ 2.4V | | 4 | | ns |

READ MODE

| Center Tap Voltage VCT | | | Vcc - 1.5 | | VDC |
|--|------------------------|------|-----------|------|-----|
| Input Bias Current (per side) | From VCT to HnX or HnY | | 20 | 60 | μА |
| Output Offset Voltage | RDX - RDY | -200 | | +200 | mV |
| Common Mode Output Voltage | RDX + RDY 2 | 2 | Vcc - 2.4 | 3.5 | VDC |
| Common Mode Output Voltage Change from Write to Read Mode | | -100 | | +100 | mV |

FAULT DETECTION CHARACTERISTICS

Unless otherwise specified recommended conditions apply, lw = 30 mA, $Lh = 5 \mu H$, F(WDI) = 10 MHz.

| Minimum Rate of WDI Input for Safe condition | 150 | | kHz |
|---|-----|-----|-----|
| Maximum Rate of WDI Input for Unsafe condition | | 50 | kHz |
| Minimum voltage value for guaranteed write current turn-on | 4.4 | | VDC |
| Maximum voltage value for guaranteed write current turn-off | | 3.9 | VDC |

ELECTRICAL SPECIFICATIONS (continued)

DYNAMIC CHARACTERISTICS AND TIMING

Unless otherwise specified, recommended operating conditions apply and Iw = 30 mA, Lh = 5 μ H, f(WDI) = 5 MHz, CL(RDX, RDY) \leq 20 pF.

WRITE MODE

| PARAMETER | CONDITIONS | MIN | NOM | MAX | UNITS |
|-----------------------------------|--------------------|-----|-----|-----|--------|
| Differential Head Voltage Swing | | 6.0 | 6.4 | | V(pk) |
| Unselected Head Transient Current | 1 μH ≤ Lh ≤ 9.5 μH | | | 2 | mA(pk) |
| Differential Output Capacitance | | | - | 15 | pF |
| Differential Output Resistance | (1203AR only) | 600 | | 960 | Ω |

READ MODE

| READ MODE | | | | | |
|--|--|------|------|-----|--------|
| Differential Voltage Gain | Vin = 1 mVrms @ 1 MHz | 200 | 250 | 300 | V/V |
| Bandwidth (-3dB) | $ Zs < 5\Omega$, Vin = 1 mVpp | 30 | 60 | | MHz |
| Input Noise Voltage | BW = 15 MHz, Lh = 0, Rh = 0 | | 0.85 | 1.2 | nV/√Hz |
| Differential Input Capacitance | Vin = 1 mVrms, $f = 5MHz$ | | 16 | 19 | pF |
| Differential Input Resistance | | | 2 | | kΩ |
| Dynamic Range | AC input voltage where gain falls to 90% of its small signal gain value, $f = 5$ MHz | 2 | | | mVpp |
| Common Mode Rejection Ratio | Vcm = 100 mVpp @ 1 MHz < f < 10 MHz | 50 | 75 | | dB |
| Power Supply Rejection Ratio | Δ Vcc =100 mVpp @ 1 MHz < f < 10 MHz | 45 | | | dB |
| Channel Separation | Unselected Channels: Vin = 20 mVpp 1 MHz < f < 10 MHz | 45 | 54 | | dB |
| RDX, RDY Single Ended Output Resistance | | | | 30 | Ω |
| Output Current | AC Coupled Load, RDX to RDY | ±1.5 | | | mA |

SWITCHING CHARACTERISTICS

| PARAMETER | | CONDITIONS MIN | | NOM | MAX | UNITS |
|--|----------------------|---|-----|------|-----|-------|
| R/W Read to Write Write to Read | | R/W to 90% of write current | | 50 | 400 | ns |
| | | R/W to 90% of 100 mV 10 MHz read signal envelope or to 10% IW | | 0.15 | 1.0 | μs |
| CS Unselect to Select Select to Unselect | | CS to 90% of 100 mV 10 MHz read signal envelope | | 1.0 | 2.0 | μs |
| | | CS to 10% Ih | | 0.05 | 0.6 | μs |
| HS0, 1 to any Head | | To 90% of 100 mV 10 MHz read signal envelope | - | | 0.6 | μs |
| WUS | Safe to Unsafe (TD1) | (1203A only) | 3.5 | | 20 | μs |
| | | (1203AR only) | 7.0 | | 30 | μs |
| | Unsafe to Safe (TD2) | Write mode, after fault cleared after 2nd transition | | | 350 | ns |
| Head C | urrent | Rh = 0, Lh = 0 | | | | |
| Prop. Delay (TD3) Asymmetry Rise/Fall Time | | From 50% points | | 25 | 40 | ns |
| | | WDI has 50% Duty Cycle and 1 ns Rise/Fall Time | | | 2 | ns |
| | | 10% - 90% Points | | 4 | 20 | ns |

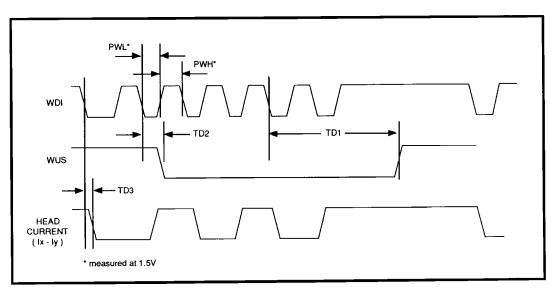
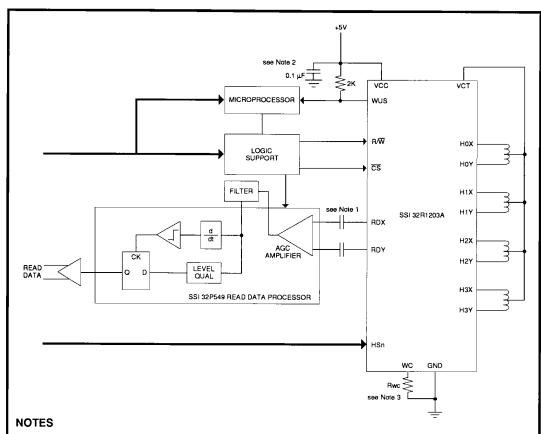


FIGURE 1: Write Mode Timing Diagram



- Limit DC current from RDX and RDY to 100 μA and load capacitance to 20 pF. In multi-chip application these outputs can be wire-OR'ed.
- 2. The power bypassing capacitor must be located close to the 32R1203A with its ground returned directly to device ground, with as short a path as possible.
- 3. To reduce ringing due to stray capacitance this resistor should be located close to the 32R1203A. Where this is not desirable a series resistor can be used to buffer a long WC line.

FIGURE 2: Applications Information

PACKAGE PIN DESIGNATIONS

(Top View)

| THERMAL CHARACTERISTICS: 01A | THERMAL | CHARACTERISTICS: | θiA |
|------------------------------|---------|------------------|-----|
|------------------------------|---------|------------------|-----|

| 20-Lead SOL, SOV 96° C/W |
|--------------------------|
|--------------------------|

| GND | 1 | | 20 | | CS |
|-----|-------|----------|----|---|-----|
| нох | 2 | | 19 | | R/W |
| H0Y | 3 | | 18 | | wc |
| H1X | 4 | 32R1203A | 17 | | RDY |
| H1Y | 5 | Channels | 16 | | RDX |
| H2X | 6 | | 15 | | HS0 |
| H2Y | 7 | | 14 | | HS1 |
| нзх | 8 | | 13 | | vcc |
| НЗҮ | 9 | | 12 | | WDI |
| VCT | 10 | | 11 | | wus |
| | | | | 1 | |

20-Lead SOL, SOV

CAUTION: Use handling procedures necessary for a static sensitive component.

ORDERING INFORMATION

| PART DESCRIPTION | ORDERING NUMBER | PACKAGE MARK |
|------------------|------------------|------------------|
| SSI 32R1203A | | |
| 20-Lead SOL | SSI 32R1203A-CL | SSI 32R1203A-CL |
| 20-Lead SOV | SSI 32R1203A-CV | SSI 32R1203A-CV |
| SSI 32R1203AR | | |
| 20-Lead SOL | SSI 32R1203AR-CL | SSI 32R1203AR-CL |
| 20-Lead SOV | SSI 32R1203AR-CV | SSI 32R1203AR-CV |

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| Notes: |
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